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Publons / Web Of Science ResearcherID: A-1113-2019

ScopusID: 57198197314

Yoksis Araştırmacı ID: 256157

Yönetilen Tezler

2023	Aydemir U., Yüksek Lisans, H.ÖZBEK(Öğrenci), Araçlarda yeni bir fiber optik merkezi aydınlatma sistemi kurgusu tasarımı ve analizi
2022	Aydemir U., Yüksek Lisans, S.GİZEM(Öğrenci), Su Altında Görünür Işık Haberleşmesi
2022	Aydemir U., Yüksek Lisans, S.LISKIN(Öğrenci), KIZİLÖTESİ IŞIK İLE İNVAZİV OLМАYAN KAN ŞEKERİÖLÇÜM SİSTEMİNİN GELİŞTİRİLMESİ
2021	Aydemir U., Yüksek Lisans, M.FATİH(Öğrenci), OTONOM ARAÇLAR İÇİN STATİK VE DİNAMİK LOGO PROJEKSİYON LAMBALARININ GELİŞTİRİLMESİ
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- XI. **Photoelectric Characteristic of the Silicon Photodiode with BCP Interfacial Layer**
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- XVI. **Illumination Dependent Admittance Characteristics of Au/Zinc Acetate Doped Polyvinyl Alcohol (PVA:Zn)/n-Si Schottky Barrier Diodes (SBDs)**
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Metrikler

Yayın: 53
Atıf (WoS): 627
Atıf (Scopus): 632
H-İndeks (WoS): 12
H-İndeks (Scopus): 13